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PCT

PATENTS

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:)
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TAUNIER ET AL.)
)
Serial No. **10/540,729**)
)
Filed: **June 24, 2005**)
)
For: **METHOD OF PRODUCING THIN**)
FILMS OF COMPOUND 1-III-VI,)
PROMOTING THE INCORPORATION)
OF III ELEMENTS IN THE FILM)

INFORMATION DISCLOSURE STATEMENT


Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

The citation of information on the attached Form PTO/SB/08, "Information Disclosure Statement by Applicant" is made pursuant to 37 C.F.R. §§ 1.97 and 1.98. A copy of the listed items is enclosed.

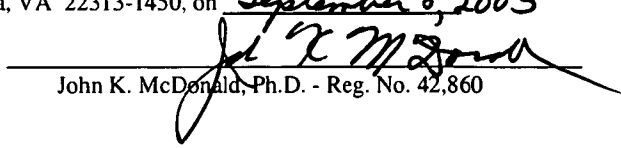
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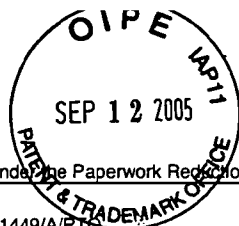
Respectfully submitted,


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Our Docket: 42528-317078

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on September 8, 2005


John K. McDonald, Ph.D. - Reg. No. 42,860



INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)		Complete if Known			
		Application Number	10/540,729		
		Filing Date	June 24, 2005		
		First Named Inventor	Stephane Taunier		
		Group Art Unit	1795		
		Examiner Name	Phasge		
Sheet		of		Attorney Docket Number	16721-0290 (42528-317078)

U.S. PATENT DOCUMENTS

Examiner Initials	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code ² (if known)			
/A.P./	1	5,275,714		Bonnet et al.	01/04/1994	
/A.P./	2	2002/0189665	A1	Bhattacharya	12/19/2002	

FOREIGN PATENT DOCUMENTS

Examiner Initials	Cite No. ¹	Foreign Patent Document			Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶
		Office ³	Number ⁴	Kind Code ⁵ (if known)				
/A.P./	3		WO 02/077322	A1	Bhattacharya, Raghu, Nath	03/22/2001		

Examiner Signature	/Arun Phasge/	Date Considered	12/21/2008
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OTHER INFORMATION - NON PATENT LITERATURE DOCUMENTS

Examiner Initials	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T ²
/A.P./	4	International Search Report	
/A.P./	5	PAULA OBREJA ET AL.; "Preparation and Properties of Electrodeposited InSe and Cu _x Se Thin Films"; Semiconductor Conference; 1998; pp. 233-236.	
/A.P./	6	FALL ET AL.; "Electrochemical and Spectroscopic Properties of Poly(3-methoxythiophene) Electrosynthesized in an Aqueous Micellar Medium"; Abstract, Database Inspec 'Online', The Institution of Electrical Engineers, Stevenage GB; XP002254320; Synthetic Metals, Elsevier, Switzerland, Vol. 93, No. 3, 31 March 1998; pp. 175-179; ISSN: 0379-6779.	

¹Unique citation designation number. ²See attached Kinds of U.S. Patent Documents. ³Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴For Japanese patent document, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶Applicant is to place a check mark here if English language translation is attached.